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4V Drive Pch MOSFET

RP1E090RP

● Structure

Silicon P-channel MOSFET

● Features

- 1) Low on-resistance.
- 2) Built-in G-S Protection Diode.
- 3) Small Surface Mount Package (MPT6).

● Application

Switching

● Packaging specifications

Type	Package	Taping
	Code	TR
	Basic ordering unit (pieces)	1000
RP1E090RP		○

● Absolute maximum ratings (Ta = 25°C)

Parameter	Symbol	Limits	Unit
Drain-source voltage	V_{DSS}	-30	V
Gate-source voltage	V_{GSS}	±20	V
Drain current	Continuous	I_D	±9 A
	Pulsed	I_{DP}^{*1}	±36 A
Source current (Body Diode)	Continuous	I_S	-1.6 A
	Pulsed	I_{SP}^{*1}	-36 A
Power dissipation	P_D^{*2}	2.0	W
Channel temperature	Tch	150	°C
Range of storage temperature	Tstg	-55 to +150	°C

*1 $P_w \leq 10 \mu s$, Duty cycle $\leq 1\%$

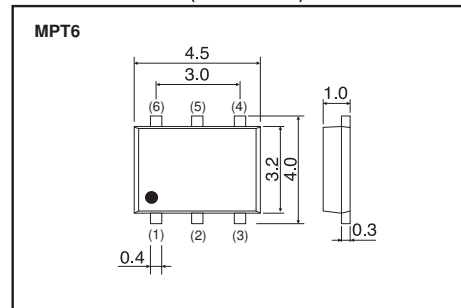
*2 Mounted on a ceramic board.

● Thermal resistance

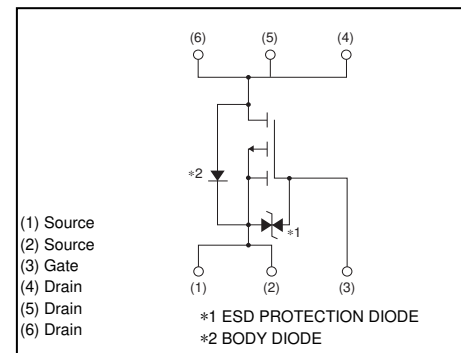
Parameter	Symbol	Limits	Unit
Channel to Ambient	$R_{th}(ch-a)^*$	62.5	°C / W

*Mounted on a ceramic board.

● Dimensions (Unit : mm)



● Inner circuit



● **Electrical characteristics** (Ta = 25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Gate-source leakage	I_{GSS}	-	-	±10	μA	$V_{GS}=\pm 20V, V_{DS}=0V$
Drain-source breakdown voltage	$V_{(BR)DSS}$	-30	-	-	V	$I_D=-1mA, V_{GS}=0V$
Zero gate voltage drain current	I_{DSS}	-	-	-1	μA	$V_{DS}=-30V, V_{GS}=0V$
Gate threshold voltage	$V_{GS(th)}$	-1.0	-	-2.5	V	$V_{DS}=-10V, I_D=-1mA$
Static drain-source on-state resistance	$R_{DS(on)}^*$	-	13	16.9	mΩ	$I_D=-9A, V_{GS}=-10V$
		-	18	25.2		$I_D=-9A, V_{GS}=-4.5V$
		-	21	29.4		$I_D=-9A, V_{GS}=-4.0V$
Forward transfer admittance	$ Y_{fs} ^*$	10	-	-	S	$I_D=-9A, V_{DS}=-10V$
Input capacitance	C_{iss}	-	3000	-	pF	$V_{DS}=-10V$
Output capacitance	C_{oss}	-	360	-	pF	$V_{GS}=0V$
Reverse transfer capacitance	C_{rss}	-	360	-	pF	$f=1MHz$
Turn-on delay time	$t_{d(on)}^*$	-	20	-	ns	$I_D=-4.5A, V_{DD}^*=-15V$
Rise time	t_r^*	-	30	-	ns	$V_{GS}=-10V$
Turn-off delay time	$t_{d(off)}^*$	-	135	-	ns	$R_L=3.3\Omega$
Fall time	t_f^*	-	80	-	ns	$R_G=10\Omega$
Total gate charge	Q_g^*	-	30	-	nC	$I_D=-9A$
Gate-source charge	Q_{gs}^*	-	7	-	nC	$V_{DD}^*=-15V$
Gate-drain charge	Q_{gd}^*	-	11	-	nC	$V_{GS}=-5V$

*Pulsed

● **Body diode characteristics** (Source-Drain) (Ta = 25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Forward Voltage	V_{SD}^*	-	-	-1.2	V	$I_s=-9A, V_{GS}=0V$

*Pulsed

● Electrical characteristic curves

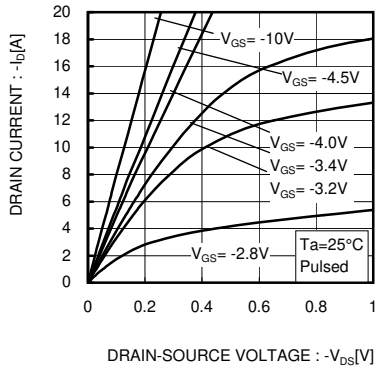


Fig.1 Typical output characteristics(I)

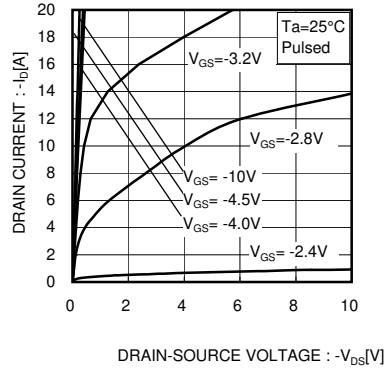


Fig.2 Typical output characteristics(II)

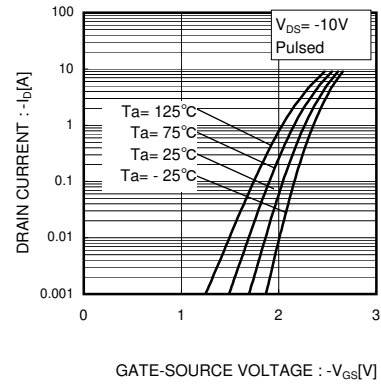


Fig.3 Typical Transfer Characteristics

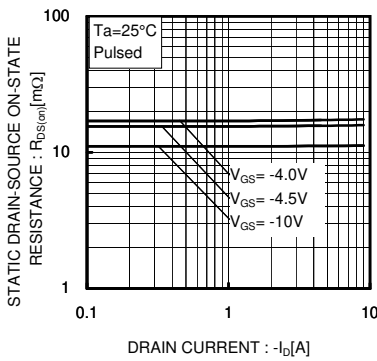


Fig.4 Static Drain-Source On-State Resistance vs. Drain Current(I)

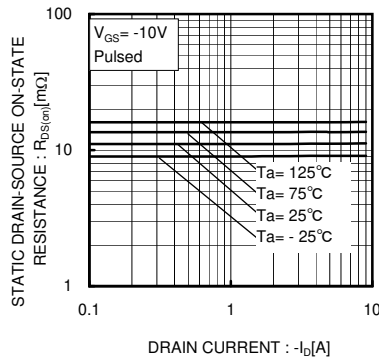


Fig.5 Static Drain-Source On-State Resistance vs. Drain Current(II)

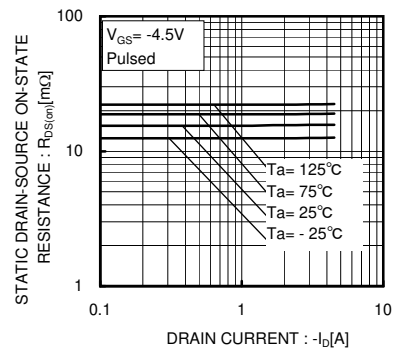


Fig.6 Static Drain-Source On-State Resistance vs. Drain Current(III)

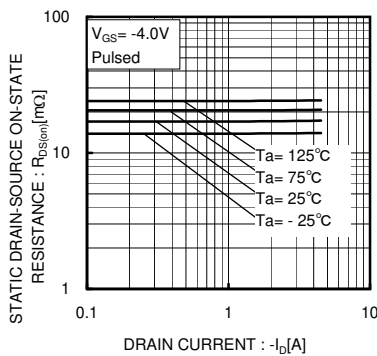


Fig.7 Static Drain-Source On-State Resistance vs. Drain

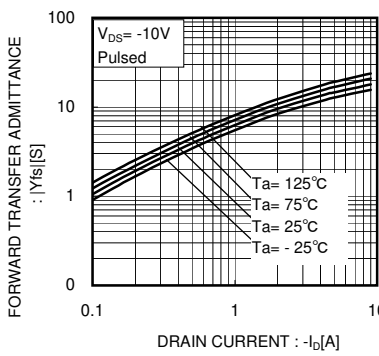


Fig.8 Forward Transfer Admittance vs. Drain Current

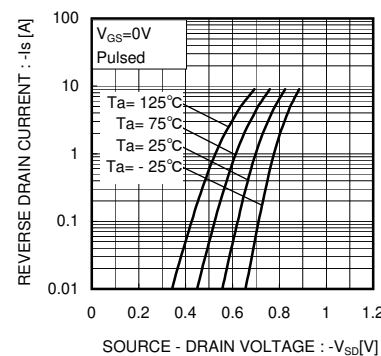


Fig.9 Reverse Drain Current vs. Source-Drain Voltage

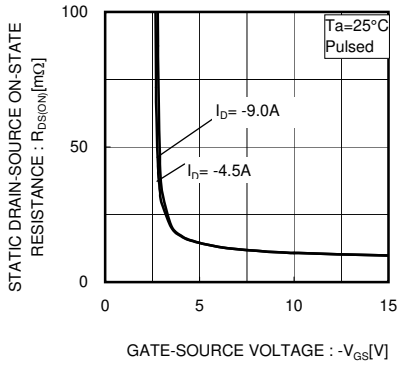


Fig.10 Static Drain-Source On-State Resistance vs. Gate Source Voltage

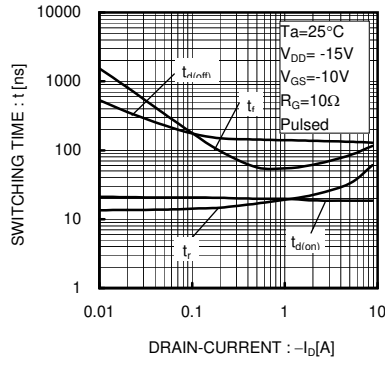


Fig.11 Switching Characteristics

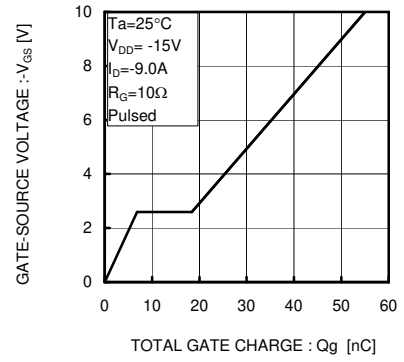


Fig.12 Dynamic Input Characteristics

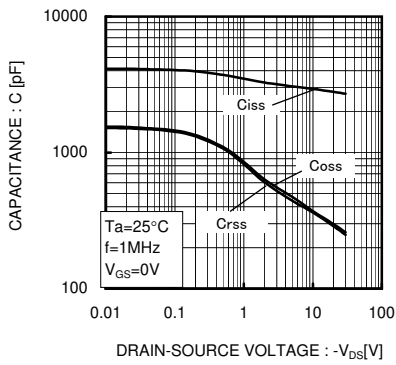


Fig.13 Typical Capacitance vs. Drain-Source Voltage

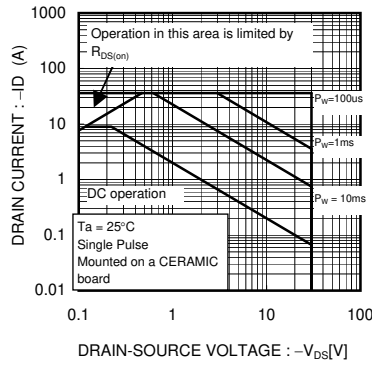


Fig.14 Maximum Safe Operating Area

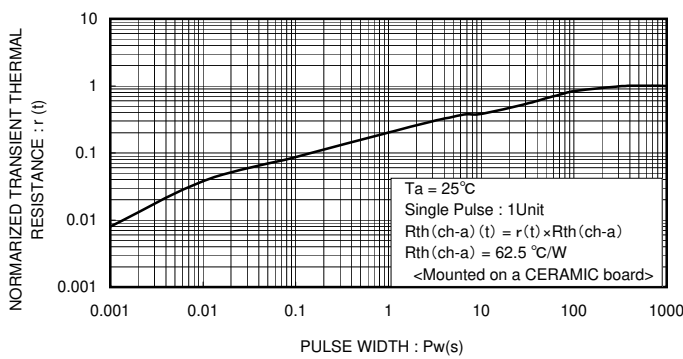


Fig.15 Normalized Transient Thermal Resistance vs. Pulse Width

● Measurement circuits

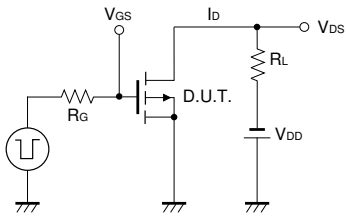


Fig.1-1 Switching Time Measurement Circuit

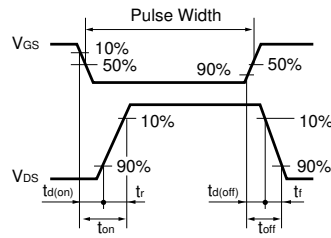


Fig.1-2 Switching Waveforms

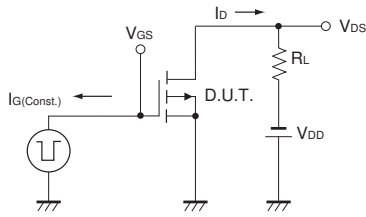


Fig.2-1 Gate charge measurement circuit

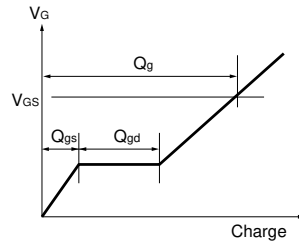


Fig.2-2 Gate Charge Waveform

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